--Docket No.

239515US2

IN RE APPLICATION OF: Keisuke YONEHAMA, et al.

SERIAL NO: 10/602,595

FILED:

June 25, 2003

FOR:

TRADE A SEMICONDUCTOR MEMORY DEVICE HAVING A GATE ELECTRODE AND A DIFFUSION LAYER

AND A MANUFACTURING METHOD THEREOF

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

## SIR:

Transmitted herewith is an amendment in the above-identified application.

- No additional fee is required
- ☐ Small entity status of this application under 37 C.F.R. §1.9 and §1.27 is claimed.
- ☐ Additional documents filed herewith:

The Fee has been calculated as shown below:

CLAIMS CLAIMS	CLAIMS REMAINING		HIGHEST NUMBER PREVIOUSLY PAID	NO. EXTRA CLAIMS		RATE		CALCULATIONS
TOTAL	30	MINUS	30	0	х	\$50	=	\$0.00
INDEPENDENT	3	MINUS	3	0	х	\$200	=	\$0.00
		☐ MULTIPL	E DEPENDENT	CLAIMS	+	\$360	=	\$0.00
		TOTAL OF ABOVE CALCULATIONS						\$0.00
		☐ Reduction	by 50% for filing	by Small Entity	,			\$0.00
	SPECIAL STREET	☐ Recordation of Assignment				\$40	=	\$0.00
						ТОТ	AL	\$0.00

- $\square$  A check in the amount of \$0.00 is attached.
- ☐ Credit card payment form is attached to cover the fees in the amount of **\$0.00**
- Please charge any additional Fees for the papers being filed herewith and for which no check or credit card payment is enclosed herewith, or credit any overpayment to deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.
- If these papers are not considered timely filed by the Patent and Trademark Office, then a petition is hereby made under 37 C.F.R. §1.136, and any additional fees required under 37 C.F.R. §1.136 for any necessary extension of time may be charged to Deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.

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**DOCKET NO: 239515US2** 

## IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

KEISUKE YONEHAMA, ET AL. : EXAMINER: OWENS, D.

SERIAL NO: 10/602,595

FILED: JUNE 25, 2003 : GROUP ART UNIT: 2811

FOR: A SEMICONDUCTOR MEMORY DEVICE HAVING A GATE ELECTRODE AND A DIFFUSION LAYER AND A MANUFACTURING METHOD THEREOF

## **AMENDMENT**

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated September 8, 2004, please amend the aboveidentified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 8 of this paper.

Remarks/Arguments begin on page 14 of this paper.